TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LVXC3245FS

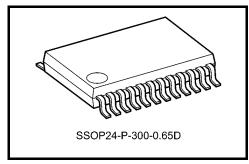
#### Dual Supply Octal Configurable Voltage Interface Bus Transceiver

The TC74LVXC3245FS is a dual supply, advanced high-speed CMOS octal configurable voltage interface bus transceiver fabricated with silicon gate CMOS technology.

Designed for use as an interface between a 3.3 V bus and a 3.3 V to 5 V bus in mixed 3.3 V/5 V supply systems' it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is intended for 2 way asynchronous communication between data busses.

The direction of data transmission is determined by the level of the DIR input. The enable input ( $\overline{G}$ ) can be used to disable the device so that the buses are effectively isolated. The A-port interfaces with



Weight: 0.14 g (typ.)

the 3.3-V bus, the B-port with the 3.3V to 5V bus. This device will allow the  $V_{CCB}$  voltage source pin and I/O pins on the B port to float when  $\overline{G}$  is "H".

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

- Bi-directional interface between 3 V and 5 V buses
- High-speed: t<sub>pd</sub> = 8.5 ns (max)

 $(V_{CCA} = 3.3 \text{ V}, V_{CCB} = 5.0 \text{ V})$ 

- Low power dissipation: I<sub>CC</sub> = 8 μA (max) (Ta = 25°C)
- Symmetrical output impedance: I<sub>OUTA</sub> = ±24 mA (min)

 $I_{OUTB} = \pm 24 \text{ mA (min)}$ 

 $(V_{CCA} = V_{CCB} = 3.0 \text{ V})$ 

- Low noise: V<sub>OLP</sub> = 1.5 V (max)
- Flexible V<sub>CCB</sub> operating range
- Allows B port and  $V_{CCB}$  to float simultaneously when  $\overline{G}$  is "H"
- Package: SSOP (shrink small outline package)

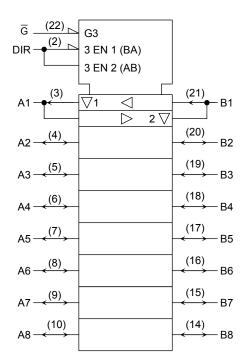
Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pin must have their input levels fixed by means of pull-up or pull-down resistors.

## Pin Assignment (top view)

#### $V_{\text{CCA}}$ 24 $V_{\text{CCB}}$ DIR 2 23 NC $\overline{\mathsf{G}}$ Α1 Α2 В1 А3 5 20 В2 A4 6 19 В3 Α5 18 B4 A6 8 В5 Α7 9 16 В6 В7 A8 10 15 GND 11 B8 GND 12 **GND**

## **IEC Logic Symbol**



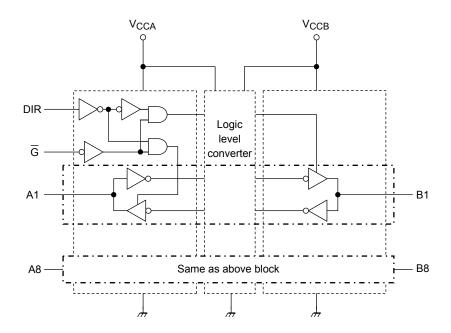
#### **Truth Table**

Inputs		Outputs	Function			
G	DIR	Outputs	A-Bus	B-Bus		
L	L	A = B	Output	Input		
L	Н	B=A	Input	Output		
Н	Х	Z	High impedance			

X: Don't care

Z: High impedance

#### **Block Diagram**



#### **Absolute Maximum Ratings (Note 1)**

Characteristics		Symbol	Rating	Unit
Supply voltage range		$V_{CCA}$	-0.5 to 7.0	V
	(Note 2)	V <sub>CCB</sub>	-0.5 to 7.0	V
DC input voltage	(DIR, $\overline{G}$ )	$V_{IN}$	-0.5 to V <sub>CCA</sub> + 0.5	V
DC bus I/O voltage		V <sub>I/OA</sub>	-0.5 to V <sub>CCA</sub> + 0.5	>
DC bus I/O voltage		V <sub>I/OB</sub>	-0.5 to V <sub>CCB</sub> + 0.5	V
Input diode current		l <sub>IK</sub>	±20	mA
Output diode current		I <sub>I/OK</sub>	±50	mA
DC output current		I <sub>OUTA</sub>	±50	mA
DC output current		I <sub>OUTB</sub>	±50	Ш
DC Va alground ourrent		I <sub>CCA</sub>	±200	mA
DC V <sub>CC</sub> /ground current		I <sub>CCB</sub>	±200	IIIA
Power dissipation		$P_{D}$	180	mW
Storage temperature		T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### Note 2: V<sub>CCB</sub> > V<sub>CCA</sub>

Don't supply a voltage to  $V_{\mbox{\scriptsize CCB}}$  terminal when  $V_{\mbox{\scriptsize CCA}}$  is in the OFF state.



## **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CCA</sub>	2.7 to 3.6	V
Supply Voltage	V <sub>CCB</sub>	3.0 to 5.5	V
Input voltage (DIR, $\overline{\overline{G}}$ )	V <sub>IN</sub>	0 to V <sub>CCA</sub>	V
Bus I/O voltage	V <sub>I/OA</sub>	0 to V <sub>CCA</sub>	V
bus 1/O voltage	V <sub>I/OB</sub>	0 to V <sub>CCB</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
		0 to 8	
Input rise and fall time	dt/dv	$(V_{CCA} = 2.7 \text{ to } 3.6 \text{ V})$	ns/V
input noe and ian time	di/dv	0 to 8	113/ V
		$(V_{CCB} = 3.0 \text{ to } 5.5 \text{ V})$	

Note: The operating ranges are required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either  $V_{CC}$  or GND. Please connect both bus inputs and the bus outputs with  $V_{CC}$  or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

## **Electrical Characteristics**

#### **DC Characteristics**

Characteri	otioo	Sym-	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
Characteris	bol rest contri		ILION	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Тур.	Max	Min	Max	Offic	
	<u> </u>			2.7	3.0	2.0	_	_	2.0	_		
Input H	$V_{IHA}$	DIR, $\overline{G}$ , An		3.0	3.6	2.0	_		2.0			
Input voltage					3.6	5.5	2.0	—	_	2.0	_	V
(V <sub>CCA</sub> )	<del>e</del>				2.7	3.0	_	_	0.8	_	8.0	-
	L-level	$V_{ILA}$	DIR, $\overline{G}$ , An		3.0	3.6	_	_	0.8	_	8.0	
					3.6	5.5	_	_	0.8	_	0.8	
	le/				2.7	3.0	2.0	_	_	2.0	_	
Input	H-level	V <sub>IHB</sub>	Bn		3.0	3.6	2.0	_		2.0		
voltage				3.6	5.5	3.85	_		3.85		V	
(V <sub>CCB</sub> )	le ve	V <sub>ILB</sub>	Bn		2.7	3.0			0.8		0.8	
	L-level				3.0	3.6		_	0.8		0.8	
				3.6	5.5		_	1.65	_	1.65		
				I <sub>OH</sub> = -100 μA	3.0	3.0	2.9	3.0	_	2.9	_	
				I <sub>OH</sub> = -12 mA	3.0	3.0	2.56	_		2.46		
	H-level	V <sub>OHA</sub>		I <sub>OH</sub> = -24 mA	3.0	3.0	2.35	_	_	2.25	_	_
Output			V <sub>INA</sub> = V <sub>IHA</sub> or	I <sub>OH</sub> = -12 mA	2.7	3.0	2.3	_	_	2.2		
voltage (V <sub>CCA</sub> )			V <sub>ILA</sub> V <sub>INB</sub> = V <sub>IHB</sub> or	I <sub>OH</sub> = -24 mA	2.7	4.5	2.1	_	_	2.0	_	V
(VCCA)			V <sub>ILB</sub>	I <sub>OL</sub> = 100 μA	3.0	3.0	_	0.0	0.1	_	0.1	
le	ıvel	<u> </u>		I <sub>OL</sub> = 24 mA	3.0	3.0	_	_	0.36	_	0.44	
	L-level	V <sub>OLA</sub>		I <sub>OL</sub> = 12 mA	2.7	3.0	_	_	0.36		0.44	
				I <sub>OL</sub> = 24 mA	2.7	4.5	_	_	0.42	_	0.5	

# **DC Characteristics (continued)**

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('haractarietice')			Sym- Test Condition				-	Ta = 25°0	5	Ta = -40 to 85°C		Unit
bol		rest Condition		V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Тур.	Max	Min	Max	Offic	
			I <sub>OH</sub> = -100 μA	3.0	3.0	2.9	3.0	_	2.9	_		
	H-level	V <sub>OHB</sub>		I <sub>OH</sub> = -12 mA	3.0	3.0	2.56	_	_	2.46	_	
Output	9I-H	VOHB	V <sub>INA</sub>	I <sub>OH</sub> = -24 mA	3.0	3.0	2.35	_	_	2.25	_	
voltage (V <sub>CCB</sub> )			= V <sub>IHA</sub> or V <sub>ILA</sub> V <sub>INB</sub>	I <sub>OH</sub> = -24 mA	3.0	4.5	3.86	_	_	3.76	_	V
(ACCR)			= V <sub>IHB</sub> or V <sub>ILB</sub>	I <sub>OL</sub> = 100 μA	3.0	3.0	_	0.0	0.1	_	0.1	
	L-level	V <sub>OLB</sub>		I <sub>OL</sub> = 24 mA	3.0	3.0	_	_	0.36	_	0.44	
				I <sub>OL</sub> = 24 mA	3.0	4.5	_	_	0.36	_	0.44	
			V <sub>INA</sub> = V <sub>IHA</sub> or V <sub>ILA</sub>		3.6	3.6	_	_	±0.5	_	±5.0	- μΑ
3-state outp	out	loza	V <sub>INB</sub> = V <sub>IHB</sub> or V <sub>ILB</sub>		3.6	5.5	_	_	±0.5	_	±5.0	
Off-state current		I <sub>OZB</sub>	$VI/OA = V_{CCA}$ or GND $VI/OB = V_{CCB}$ or GND		3.6	3.6	_	_	±0.5	_	±5.0	
					3.6	5.5	_	_	±0.5	_	±5.0	
Input leaka	ge		V <sub>IN</sub> (DIR, $\overline{G}$ )		3.6	3.6	_	_	±0.1	_	±1.0	^
current	•	I <sub>IN</sub>	= V <sub>CCA</sub> or GND		3.6	5.5	_	_	±0.1	_	±1.0	μΑ
		Ісст	PER INPUT: $V_{INA} = V_{CCA} - 0.6 \text{ V}$ $V_{INA} = V_{CCB} - 0.6 \text{ V}$ $An = V_{CCA} \text{ or GND}$ $Bn = Open,$ $\overline{G} = V_{CCA}$ $DIR = V_{CCA},$ $V_{CCB} = Open$		3.6	3.6		_	0.35	_	0.5	mA
		I <sub>CCA1</sub>			3.6	Open	-	_	5	_	50	μА
		locas	V <sub>INA</sub> = V <sub>IHA</sub> or V <sub>ILA</sub>		3.6	3.6	_	_	5	_	50	
		ICCA2	V <sub>INB</sub> = V <sub>IHB</sub> or V <sub>ILB</sub>		3.6	5.5	_	_	5	_	50	
		loca	V <sub>INA</sub> = V <sub>IHA</sub> or V <sub>IL</sub>	.A	3.6	3.6		_	5	_	50	
		ICCB	$V_{INB} = V_{IHB}$ or $V_{IL}$	.B	3.6	5.5		_	8	_	80	

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# AC Characteristics (input: $t_r = t_f = 3 \text{ ns, } C_L = 50 \text{ pF, } R_L = 500 \ \Omega)$

Characteristics	Symbol Test Condition				Ta = 25°C			Ta = -40 to 85°C		Unit			
Characteristics	Symbol	rest condition	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Тур.	Max	Min	Max	Offic			
Propagation delay time	$t_{pLH}$			5.0 ± 0.5	_	5.7	8.0	1.0	8.5	ns			
$(An \rightarrow Bn)$	$t_{pHL}$	Input: An Output: Bn		3.3 ± 0.3		6.2	8.5	1.0	9.0	115			
3-state output enable time	$t_{pZL}$		2.7 to 3.6	5.0 ± 0.5	_	6.5	9.5	1.0	10.0	ns			
$(\overline{G} \to Bn)$	$t_{pZH}$	(DIR = "H")	2.7 10 3.0	$3.3\pm0.3$	_	7.4	10.5	1.0	11.5	115			
3-state output disable time	$t_{pLZ}$			5.0 ± 0.5	_	7.3	9.5	1.0	10.0	ns			
$(\overline{G} \to Bn)$	$t_{pHZ}$			3.3 ± 0.3		6.6	9.5	1.0	10.0	115			
Propagation delay time	t <sub>pLH</sub>	- Input: Bn Output: An - (DIR = "L")		5.0 ± 0.5		4.6	7.5	1.0	8.0	ns			
$(Bn \rightarrow An)$	$t_{pHL}$		Output: An	Output: An		$3.3\pm0.3$	_	5.2	7.5	1.0	8.0	115	
3-state output enable time	t <sub>pZL</sub>				Output: An	2.7 to 3.6	5.0 ± 0.5		7.0	10.5	1.0	11.5	
$(\overline{G} \to An)$	$t_{pZH}$						2.7 10 3.0	3.3 ± 0.3		7.0	10.5	1.0	11.5
3-state output disable time	t <sub>pLZ</sub>			5.0 ± 0.5		6.1	9.5	1.0	10.0	ns			
$(\overline{G} \to An)$	$t_{pHZ}$			3.3 ± 0.3		6.0	9.5	1.0	10.0	115			
Output to output skew	t <sub>osLH</sub>	(Note 1)	2.7 to 3.6	5.0 ± 0.5	_	_	1.5	_	1.5	ns			
Output to output skew	t <sub>osHL</sub>	(Note 1)		3.3 ± 0.3		_	1.5		1.5				
Input capacitance	C <sub>INA</sub>	DIR, G				5	10		10	pF			
Bus input capacitance	C <sub>I/O</sub>	An, Bn				8	_		_	pF			
	C ·	A → B (DIR = "H")			_	4	_	_	_				
Power dissipation capacitance	C <sub>PDA</sub>	$ \begin{array}{c} A \\ B \to A \\ (DIR = "L") \end{array} $	3.3 ± 0.3	5.0 ± 0.5	_	38	_	_	_	pF			
(Note 2)	C <sub>PDB</sub>	A → B (DIR = "H")			_	88		_	_	рΓ			
		$B \rightarrow A$ (DIR = "L")			_	7	_	_					

Note 1: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, \ t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$ 

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per bit)}$ 

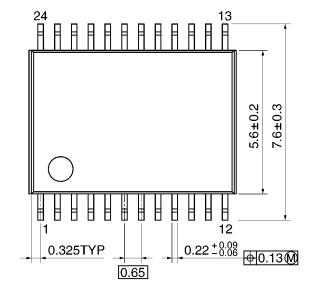
# Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF, $R_L = 500~\Omega$ )

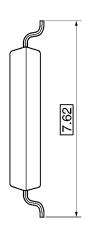
Observatoristics			T 10 W			_		
Characteristics		Symbol	Test Condition	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Тур.	Limit	Unit
Quiet output maximum	V <sub>OL</sub> (A)	V <sub>OLPA</sub>	Variation Institute Dis		3.3	_	0.9	
dynamic	VOL (A)	VOLPA	Input: Bn	3.3	5.0	_	0.9	
Quiet output mimimum	Vo. (A)	Volva	Output: An  VOLVA (DIR = "L")		3.3	_	-0.9	
dynamic	V <sub>OL</sub> (A)	V <sub>OLVA</sub>		3.3	5.0	_	-0.9	V
Quiet output maximum				3.3	3.3	_	0.8	V
dynamic	V <sub>OL</sub> (B)	V <sub>OLPB</sub>	Input: An Output: Bn	3.3	5.0	_	1.5	
Quiet output mimimum	Va. (B)	\/	(DIR = "H")	3.3	3.3	_	-0.8	
dynamic	V <sub>OL</sub> (B)	V <sub>OLVB</sub>	/B (DIR = H)	3.3	5.0	_	-1.2	
Minimum high level dynamic	V <sub>IH</sub> (A)	\/	Input: An	3.3	3.3	_	2.0	· v
input voltage		$V_{IHDA}$		3.3	5.0	_	2.0	
Maximum low level dynamic	V <sub>111</sub> (Δ)	\/	Input: An	3.3	3.3	_	0.8	V
input Voltage	V <sub>IL</sub> (A)	$V_{ILDA}$	input. An	3.3	5.0	_	0.8	'
Minimum high level dynamic	\/(P)	V	Input: Pn	3.3	3.3	2.0	_	V
input voltage	V <sub>IH</sub> (B)	V <sub>IHDB</sub>	Input: Bn	3.3	5.0	3.5	_	V
Maximum low level dynamic	\/ (D)		Input: Bn	3.3	3.3	8.0	_	V
input voltage	V <sub>IL</sub> (B)	$V_{ILDB}$	IIIput. DII	3.3	5.0	1.5	_	V

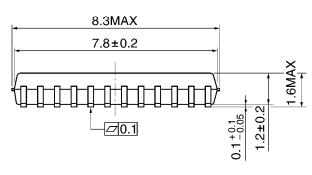
## **Package Dimensions**

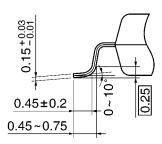
SSOP24-P-300-0.65D

Unit: mm









Weight: 0.14 g (typ.)

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